



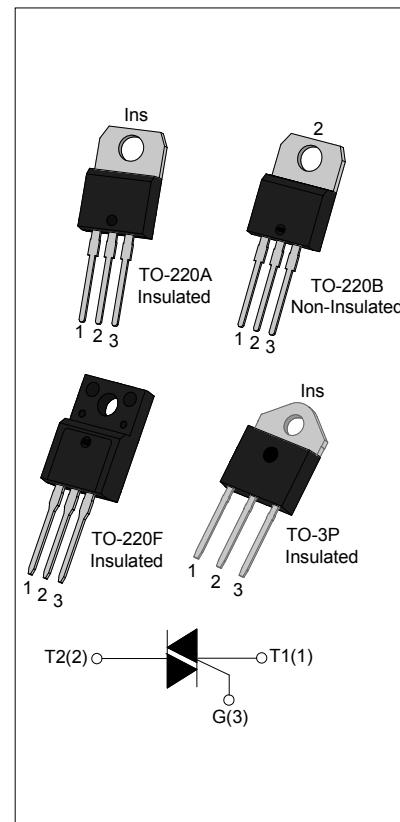
## JST20 Series 20A TRIACs

Rev.7.0

## DESCRIPTION:

With high ability to withstand the shock loading of large current, JST20 series triacs provide high dv/dt rate with strong resistance to electromagnetic interface. With high commutation performances, 3 quadrants products especially recommended for use on inductive load.

From all three terminals to external heatsink, JST20A and JST20Z provide a rated insulation voltage of 2500 V<sub>RMS</sub>, and JST20F provides a rated insulation voltage of 2000V<sub>RMS</sub>, complying with UL standards (File ref: E252906).



## MAIN FEATURES

Symbol	Value	Unit
I <sub>T(RMS)</sub>	20	A
V <sub>DRM</sub> / V <sub>RRM</sub>	600/800/1200	V

## ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T <sub>stg</sub>	-40-150	°C
Operating junction temperature range	T <sub>j</sub>	-40-125	°C
Repetitive peak off-state voltage (T <sub>j</sub> =25°C)	V <sub>DRM</sub>	600/800/1200	V
Repetitive peak reverse voltage (T <sub>j</sub> =25°C)	V <sub>RRM</sub>	600/800/1200	V
Non repetitive surge peak Off-state voltage	V <sub>DSM</sub>	V <sub>DRM</sub> +100	V
Non repetitive peak reverse voltage	V <sub>RSM</sub>	V <sub>RRM</sub> +100	V
RMS on-state current	TO-220A(Ins) (T <sub>c</sub> =70°C)	20	A
	TO-220B(Non-Ins) (T <sub>c</sub> =90°C)		
	TO-220F(Ins) (T <sub>c</sub> =65°C)		
	TO-3P(Ins) (T <sub>c</sub> =105°C)		

Non repetitive surge peak on-state current (full cycle, F=50Hz)	I <sub>TSM</sub>	200	A
I <sup>2</sup> t value for fusing (tp=10ms)	I <sup>2</sup> t	200	A <sup>2</sup> s
Critical rate of rise of on-state current (I <sub>G</sub> =2×I <sub>GT</sub> )	dI/dt	100	A/μs
Peak gate current	I <sub>GM</sub>	4	A
Average gate power dissipation	P <sub>G(AV)</sub>	1	W
Peak gate power	P <sub>GM</sub>	10	W

**ELECTRICAL CHARACTERISTICS** (T<sub>j</sub>=25°C unless otherwise specified)

## 3 Quadrants

Symbol	Test Condition	Quadrant	Value		Unit	
			BW	CW		
I <sub>GT</sub>	V <sub>D</sub> =12V R <sub>L</sub> =33Ω	I - II -III	MAX	50	35	mA
V <sub>GT</sub>		I - II -III	MAX	1.3		V
V <sub>GD</sub>	V <sub>D</sub> =V <sub>DRM</sub> T <sub>j</sub> =125°C R <sub>L</sub> =3.3KΩ	I - II -III	MIN	0.2		V
I <sub>L</sub>	I <sub>G</sub> =1.2I <sub>GT</sub>	I -III	MAX	70	60	mA
		II		90	70	
I <sub>H</sub>	I <sub>T</sub> =100mA	MAX	60	50	mA	
dV/dt	V <sub>D</sub> =2/3V <sub>DRM</sub> Gate Open T <sub>j</sub> =125°C	MIN	1000	500	V/μs	

## 4 Quadrants

Symbol	Test Condition	Quadrant		Value	Unit
I <sub>GT</sub>	V <sub>D</sub> =12V R <sub>L</sub> =33Ω	I - II -III	MAX	50	mA
		IV		70	
V <sub>GT</sub>	ALL	MAX		1.3	V
V <sub>GD</sub>	V <sub>D</sub> =V <sub>DRM</sub> T <sub>j</sub> =125°C R <sub>L</sub> =3.3KΩ	ALL	MIN	0.2	V
I <sub>L</sub>	I <sub>G</sub> =1.2I <sub>GT</sub>	I -III-IV	MAX	70	mA
		II		90	
I <sub>H</sub>	I <sub>T</sub> =100mA	MAX		60	mA
dV/dt	V <sub>D</sub> =2/3V <sub>DRM</sub> Gate Open T <sub>j</sub> =125°C	MIN		500	V/μs

## STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX)	Unit
$V_{TM}$	$I_{TM} = 28A$	$t_p = 380\mu s$	$T_j = 25^\circ C$	1.5 V
$I_{DRM}$	$V_D = V_{DRM}$ $V_R = V_{RRM}$	$T_j = 25^\circ C$	5 $\mu A$	
$I_{RRM}$		$T_j = 125^\circ C$	2.5 mA	

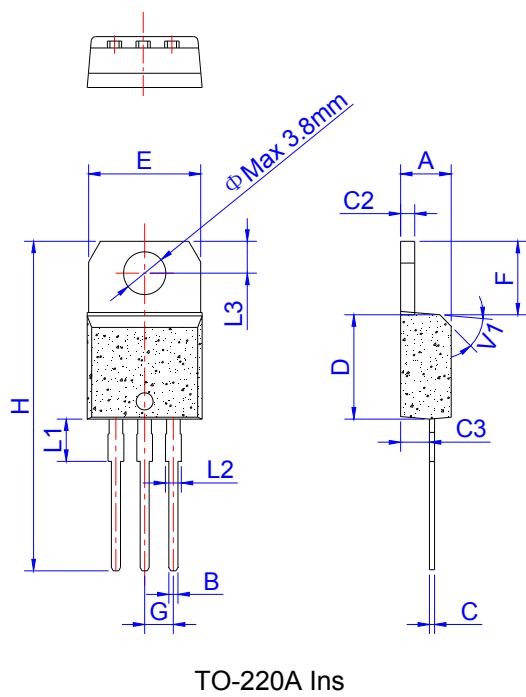
## THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case(AC)	TO-220A(Ins)	1.9
		TO-220B(Non-Ins)	1.1
		TO-220F(Ins)	2.1
		TO-3P	0.7

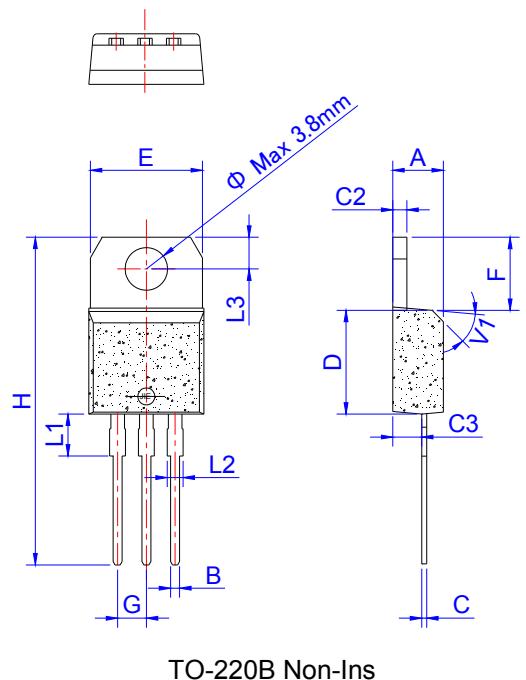
## ORDERING INFORMATION

J	ST	20	Z	-800	BW
JieJie Microelectronics Co.,Ltd	Triacs	$I_{T(RMS)}:20A$			BW: $I_{GT1-3} \leq 50mA$ CW: $I_{GT1-3} \leq 35mA$ B: $I_{GT1-3} \leq 50mA$ $I_{GT4} \leq 70mA$  600: $V_{DRM} \wedge V_{RRM} \geq 600V$ 800: $V_{DRM} \wedge V_{RRM} \geq 800V$ 1200: $V_{DRM} \wedge V_{RRM} \geq 1200V$

## PACKAGE MECHANICAL DATA

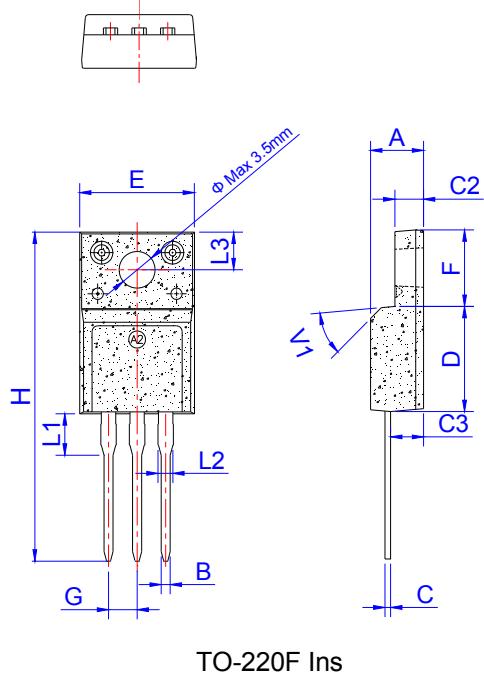


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.61		0.88	0.024		0.035
C	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.80		10.4	0.386		0.409
F	6.55		6.95	0.258		0.274
G		2.54			0.1	
H	28.0		29.8	1.102		1.173
L1		3.75			0.148	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	

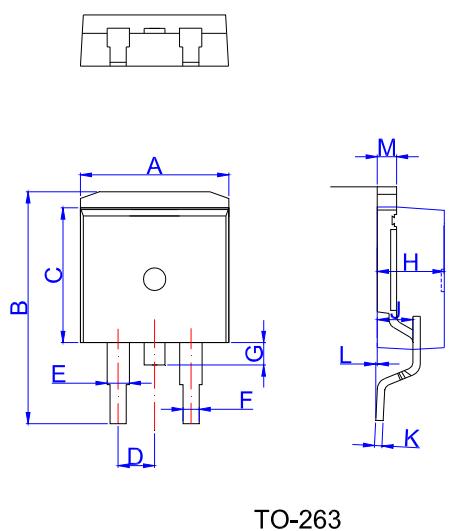


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.61		0.88	0.024		0.035
C	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.60		10.4	0.378		0.409
F	6.20		6.60	0.244		0.260
G		2.54			0.1	
H	28.0		29.8	1.102		1.173
L1		3.75			0.148	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	

## PACKAGE MECHANICAL DATA

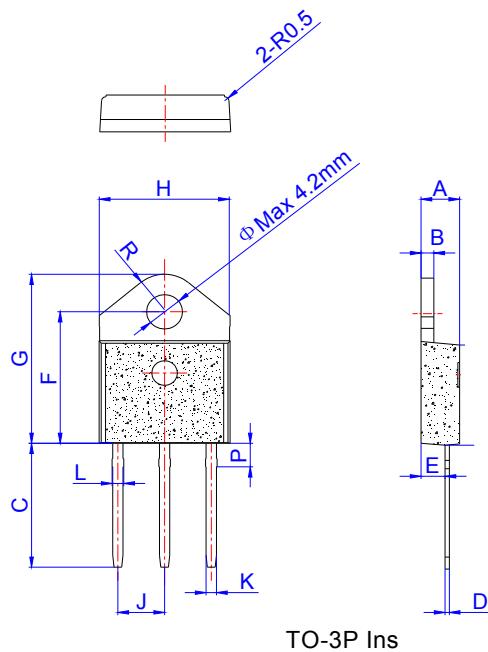


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.50		4.90	0.177		0.193
B	0.74	0.80	0.83	0.029	0.031	0.033
C	0.47		0.65	0.019		0.026
C2	2.45		2.75	0.096		0.108
C3	2.60		3.00	0.102		0.118
D	8.80		9.30	0.346		0.366
E	9.80		10.4	0.386		0.410
F	6.40		6.80	0.252		0.268
G		2.54			0.1	
H	28.0		29.8	1.102		1.173
L1		3.63			0.143	
L2	1.14		1.70	0.045		0.067
L3		3.30			0.130	
V1		45°			45°	



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	9.90		10.20	0.390		0.402
B	14.70		15.80	0.579		0.622
C	9.4		9.6	0.37		0.378
D		2.54			0.100	
E	1.20		1.40	0.047		0.055
F	0.75		0.85	0.029		0.033
G			1.75			0.069
H	4.40		4.70	0.173		0.185
J	2.30		2.70	0.091		0.106
K	0.38		0.55	0.015		0.022
L	0	0.10	0.25	0	0.004	0.010
M	1.25		1.35	0.049		0.053

## PACKAGE MECHANICAL DATA

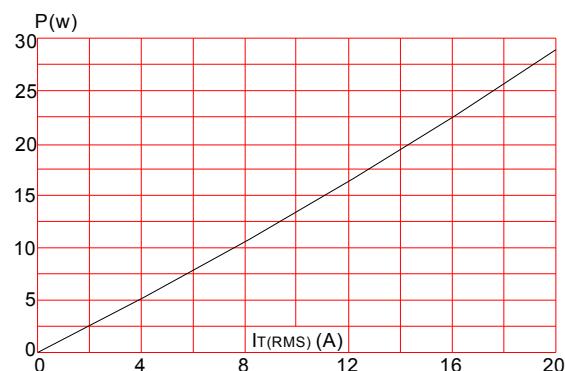


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	1.45		1.55	0.057		0.061
C	14.35		15.60	0.565		0.614
D	0.50		0.70	0.020		0.028
E	2.70		2.90	0.106		0.114
F	15.80		16.50	0.622		0.650
G	20.40		21.10	0.803		0.831
H	15.10		15.50	0.594		0.610
J	5.40		5.65	0.213		0.222
K	1.10		1.40	0.043		0.055
L	1.35		1.50	0.053		0.059
P	2.80		3.00	0.110		0.118
R		4.35			0.171	

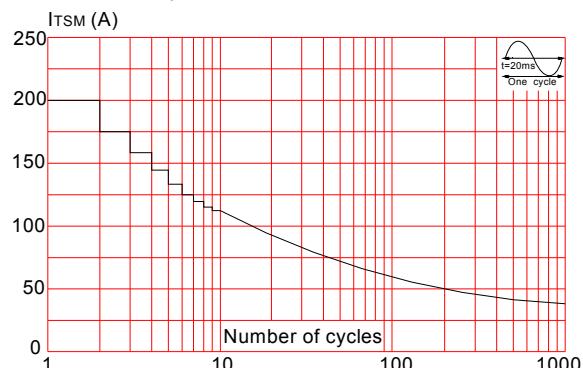
## PACKAGE INFORMATION

PACKAGE	WEIGHT (PER PCS)	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-220A	2.308g	TUBE	50	1,000	8,000
TO-220B	1.935g	TUBE	50	1,000	8,000
TO-220F	2.093g	TUBE	50	1,000	8,000
TO-3P	4.63g	TUBE	30	450	3,600

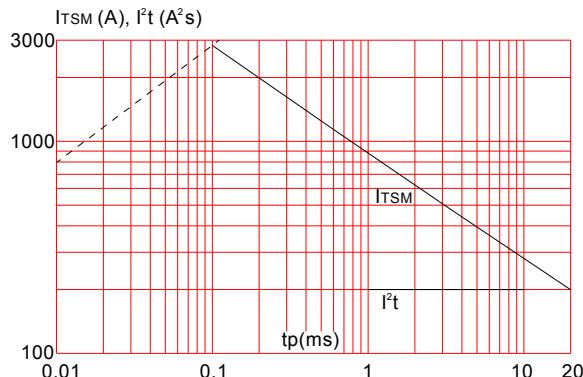
**FIG.1** Maximum power dissipation versus RMS on-state current



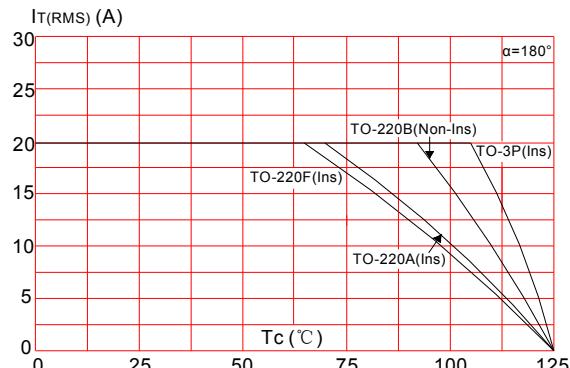
**FIG.3:** Surge peak on-state current versus number of cycles



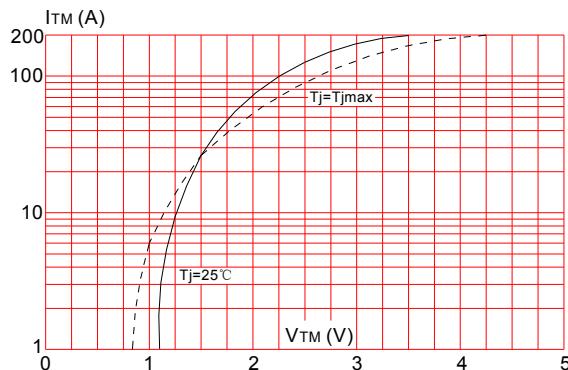
**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $tp < 20\text{ms}$ , and corresponding value of  $I^2t$  ( $dI/dt < 100\text{A}/\mu\text{s}$ )



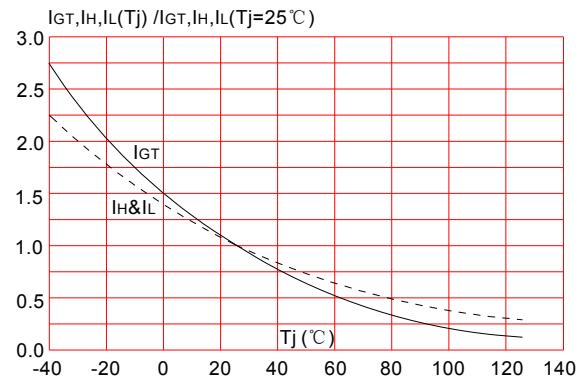
**FIG.2:** RMS on-state current versus case temperature



**FIG.4:** On-state characteristics (maximum values)



**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature



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